Application No. 10/697,647

Amendment under 37 C.F.R. §1.111 dated January 19, 2005

Response to the Office Action of October 19, 2004

Amendments to the Claims

Listing of claims:

This listing of claims replaces all prior versions and listings of claims in the application.

Claim 1 (Currently Amended): An electron beam apparatus comprising [[;]]:

an electron gun for directing a plurality of primary electron beams onto a sample [[,]];

an accelerator for accelerating objective lens for forming an electric field to accelerate a

plurality of secondary electron beams emitted from said sample;

a separator for separating said [[a]] plurality of secondary electron beams from a primary

optical system [[;]] and a director for directing said plurality of secondary electron beams into a

secondary optical system for guiding to a detector outputting a detection signal of the secondary

electron beams; and

a plate having a plurality of apertures corresponding to said plurality of secondary

electron beams in front of said detector.

a deflector for deflecting said secondary electron beams in said secondary optical system,

wherein said deflector is controlled to deflect said plurality of secondary electron beams

synchronously with scanning of said plurality of primary electron beams, thereby preventing said

plurality of secondary electron beams from moving on said detector in response to the scanning

of said plurality of primary electron beams.

Claim 2 (Currently Amended): An electron beam apparatus according to claim 1, wherein

said plurality of primary electron beams and said plurality of secondary electron beams are

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arranged in the vicinity of an optical axis, and said plurality of apertures are formed in the shape

of an ellipse which is longer in a radial direction, an X-axis direction of XY-coordinates, and/or a

Y-axis direction of the XY-coordinates from the optical axis in a plane orthogonal to the optical

axis.

Claim 3 (Currently Amended): An electron beam apparatus according to claim 1, further

comprising:

a number of memories twice as much as [[the]] a number of said detectors for storing

digital signals generated by A/D converting the detection signals [[,]]; and

change-over switches disposed in front of and at [[the]] a back of said memories, wherein

the detection signals from said detectors are input in one of said memories while the previous

detection signals stored in another of said memories are transmitted into a CPU or an image

processing unit.

Claim 4 (Currently Amended): An electron beam apparatus according to claim 1, further

comprising a deflector for deflecting said secondary electron beams in said secondary optical

system, wherein said deflector is controlled to deflect said plurality of secondary electron beams

asynchronously with scanning of said plurality of primary electron beams, thereby preventing

said plurality of secondary electron beams from moving on said second aperture plate in response

to the scanning of said plurality of primary electron beams a plate having a plurality of apertures

corresponding to said plurality of secondary electron beams in front of said detector.

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Claim 5 (Currently Amended): An electron beam apparatus comprising [[;]]:

an electron gun having a cathode member electrode, a Wehnelt member electrode, and an anode member electrode [[,]];

wherein a portion of said Wehnelt member electrode comprises a first portion adjacent to said cathode member electrode and a second portion ean be separated from the rest of said Wehnelt member, said first portion, said first portion being and can be finely moved moveable in an x-direction, a y-direction, or a z-direction orthogonal to one another.

Claim 6 (Currently Amended): An electron beam apparatus according to claim 5,

eomprising an wherein said electron gun which has comprises a multi-emitter machined as a cathode including a plurality of emitters integrated thereon, a heater for heating said multi-emitter, a supporter supporter for fixing said multi-emitter and said heater at given positions, a Wehnelt electrode, and a fine adjustment mechanism for finely adjusting the position of a portion of said Wehnelt electrode which is adjacent to said multi-emitter,

wherein [[:]] said fine adjustment mechanism is configured to be able to finely adjust the position of said portion of said Wehnelt electrode in at least one of an x-direction, a y-direction, and a θ -direction in a plane parallel to a plane which includes said multi-emitter, and a tilt direction in a plane perpendicular to said plane.

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Claim 7 (Original): An electron beam apparatus according to claim 6, wherein said fine

adjustment mechanism in the θ -direction or tilt direction is disposed at a z-position substantially

identical to said emitter.

Claim 8 (Original): An electron beam apparatus according to claim 6, wherein said

portion of said Wehnelt electrode has a plurality of small holes corresponding to said plurality of

emitters, and has a thickness of 200 µm or less only in the vicinity of said holes.

Claim 9 (Currently Amended): An electron beam apparatus according to claim 5,

wherein said electron beam apparatus forms a plurality of narrowed electron beams from

emissions of said electron gun, scans a sample surface with said electron beams [[,]] and detects

secondary electron beams formed of secondary electrons emitted from scanned positions on said

sample surface using a plurality of detectors.

Claim 10 (Currently Amended): A device manufacturing method characterized by

evaluating a wafer after the end of each wafer process for at least one wafer process using an

electron beam apparatus according to claim-1 An electron beam apparatus, comprising:

an electron gun for directing a plurality of primary electron beams onto a sample;

an objective lens for forming an electric field to accelerate a plurality of secondary

electron beams emitted from said sample;

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a separator for separating said plurality of secondary electron beams from a primary optical system; [[and]]

a director for directing said plurality of secondary electron beams into a secondary optical system for guiding to a detector outputting a detection signal of the secondary electron beams; and

an ExB separator disposed between the objective lens and former stage lens in the primary optical system for separating said secondary electron beams.

Claim 11 (Currently Amended): An electron beam apparatus for directing a plurality of primary electron beams onto a sample, comprising [[;]]:

an electron gun for directing a plurality of primary electron beams onto a sample, an accelerator for objective lens for forming an electric field to accelerating accelerate a plurality of secondary electron beams emitted from said sample;

a separator for separating said [[a]] plurality of secondary electron beams from a primary optical system; and

a director for directing said plurality of secondary electron beams into a secondary optical system for guiding to a detector outputting a detection signal of the secondary electron beams[[; and]]

wherein an ExB separator deposited between the objective lens and the former stage lens in the primary optical-system for separating said a secondary electron image is focused around said separator.

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Claim 12 (Currently Amended): An electron beam apparatus for directing a plurality of primary electron beams onto a sample, comprising:

an accelerator for accelerating a plurality of secondary electron beams emitted from said sample;

a separator for separating said secondary electron beams from a primary optical system; and

a director for directing said plurality of secondary electron beams into a secondary optical system for guiding to a detector outputting a detection signal of the secondary electron beams; wherein a secondary electron image is <u>focussed</u> around the separator.